

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
-60V	4.2Ω@-10V	-0.13A
	4.5Ω@-4.5V	

Feature

- Energy Efficient
- Low Threshold Voltage
- High-speed Switching
- ESD Protected

Application

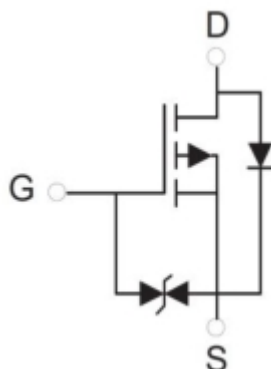
- DC-DC converters
- load switching
- power management in portable
- battery-powered products

Package

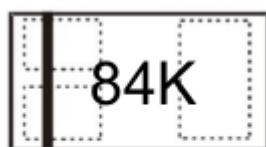


DFN1006-3

Circuit diagram



Marking



84K =Device Code

Absolute maximum ratings

($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-60	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	-0.13	A
Plused Drain Current@ $t_p < 10\mu\text{s}$	I_{DM}	-0.52	A
Power Dissipation	P_D	0.15	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	833	$^{\circ}\text{C/W}$
Junction Temperature	T_J	150	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	-55~ +150	$^{\circ}\text{C}$

Electrical characteristics

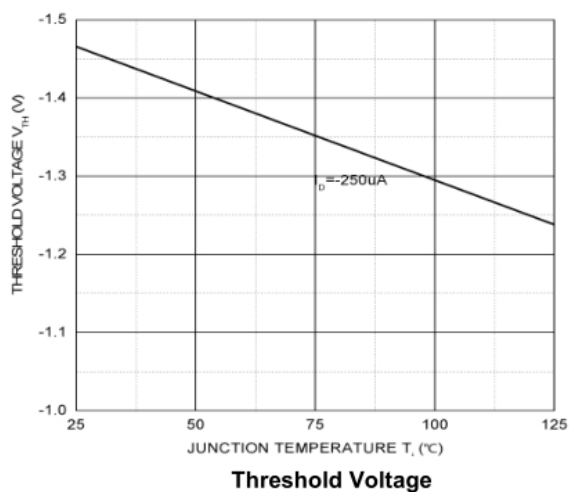
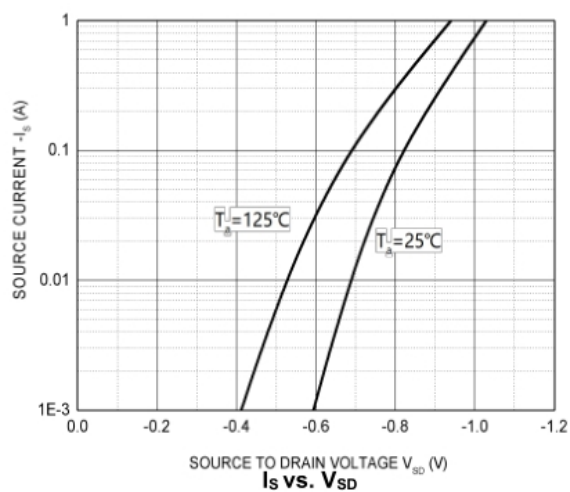
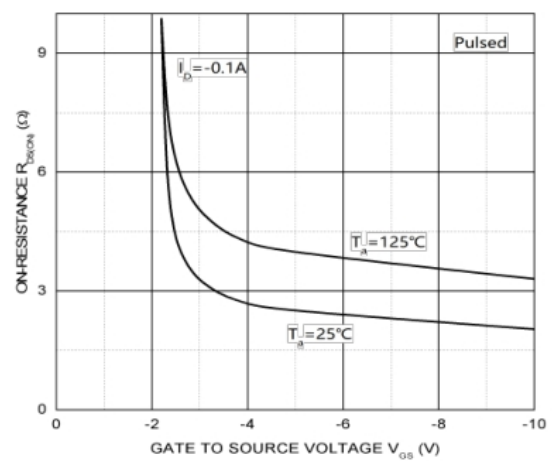
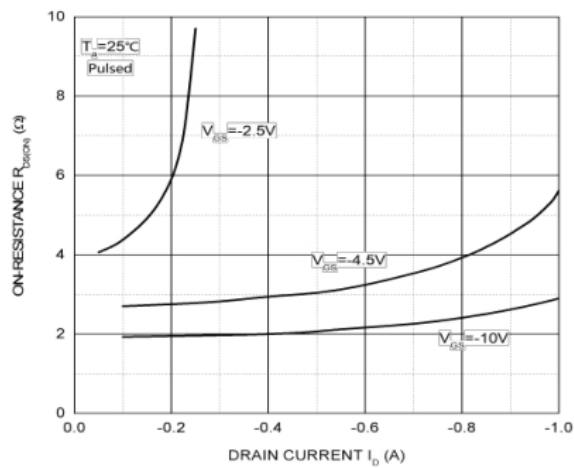
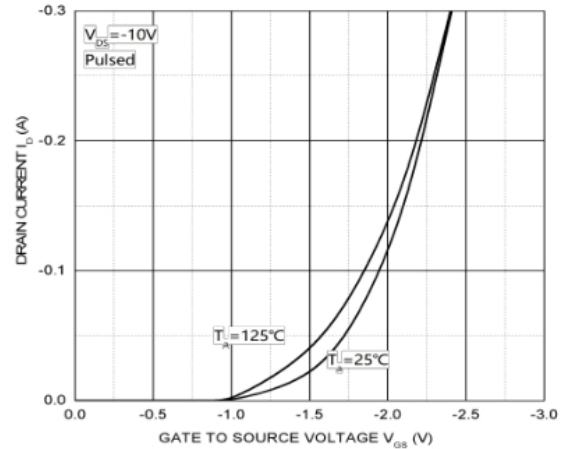
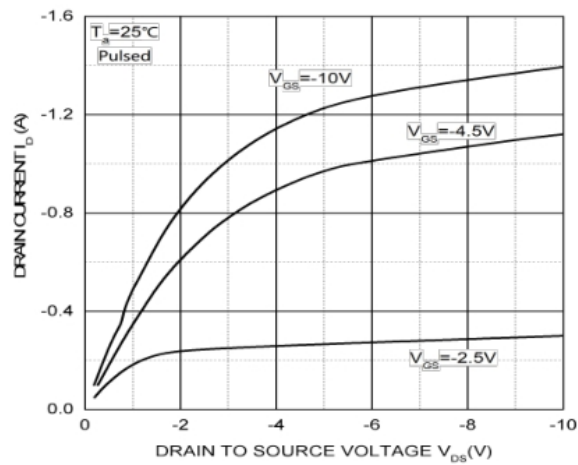
(T_A=25°C, unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = -250\mu A$	-60			V
Drain Leakage Current	I_{DSS}	$V_{DS} = -48V, V_{GS} = 0V$			-1	μA
Gate-body leakage current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			± 10	μA
Gate threshold voltage ³⁾	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-0.8	-1.5	-2.5	V
Drain-source on-resistance ³⁾	$R_{DS(on)}$	$V_{GS} = -10V, I_D = -0.15A$		4.2	6	Ω
		$V_{GS} = -4.5V, I_D = -0.15A$		4.5	7	
Dynamic characteristics ⁴⁾						
Input Capacitance	C_{iss}	$V_{DS} = -5V, V_{GS} = 0V,$ $f = 1MHz$		30		pF
Output Capacitance	C_{oss}			10		
Reverse Transfer Capacitance	C_{rss}			5		
Switching Characteristics ⁴⁾						
Turn-on delay time	$t_{d(on)}$	$V_{DD} = -15V, R_L = 50\Omega,$ $I_D = -2.5A,$		2.5		ns
Rise time	t_r			1		
Turn-off delay time	$t_{d(off)}$			16		
Turn-off fall time	t_f			8		
Source-Drain Diode Characteristics						
Diode Forward voltage	V_{SD}	$V_{GS} = 0V, I_S = -0.5A$			-1.3	V

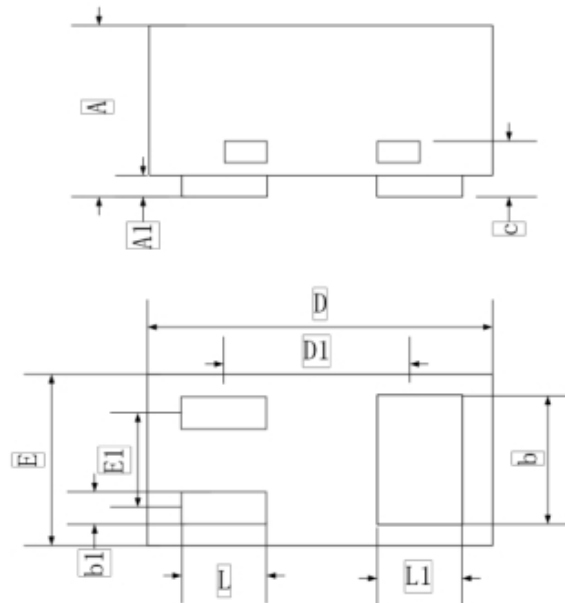
Notes:

- 1.Repetitive rating: Pulse width limited by junction temperature.
- 2.Surface mounted on FR4 board, t ≤ 10s.
- 3.Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.
- 4.Guaranteed by design, not subject to production.

Typical Characteristics



DNF1006-3L Package Information



Symbol	Dimensions in millimeters	
	Min.	Max.
A	0.46	0.51
A1	0	0.05
b	0.45	0.55
b1	0.1	0.2
c	0.08	0.18
D	0.95	1.05
D1	0.65	
E	0.55	0.65
E1	0.325	
L	0.2	0.3
L1	0.2	0.3